

# NPN SILICON RF TRANSISTOR 2SC5507

### NPN SILICON RF TRANSISTOR FOR LOW CURRENT, LOW-NOISE, HIGH-GAIN AMPLIFICATION FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04)

#### **FEATURES**

- · Low noise and high gain with low collector current
- NF = 1.2 dB TYP., Ga = 16 dB TYP. @ VcE = 2 V, Ic = 2 mA, f = 2 GHz
- Maximum stable power gain: MSG = 22 dB TYP. @ VcE = 2 V, Ic = 5 mA, f = 2 GHz
- f<sub>T</sub> = 25 GHz technology adopted
- Flat-lead 4-pin thin-type super minimold (M04) package

#### ORDERING INFORMATION

Part Number	Quantity	Supplying Form		
2SC5507	50 pcs (Non reel)	8 mm wide embossed taping		
2SC5507-T2	3 kpcs/reel	Pin 1 (Emitter), Pin 2 (Collector) face the perforation side of the tape		

**Remark** To order evaluation samples, contact your nearby sales office. The unit sample quantity is 50 pcs.

### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vcво	15	٧
Collector to Emitter Voltage	Vceo	3.3	٧
Emitter to Base Voltage	VEBO	1.5	٧
Collector Current	lc	12	mA
Total Power Dissipation	Ptot Note	39	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	−65 to +150	°C

Note Free Air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

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The mark ★ shows major revised points.

Printed in Japan



### THERMAL RESISTANCE

Parameter	Symbol	Ratings	Unit
Junction to Case Resistance	Rth j-c	240	°C/W
Junction to Ambient Resistance	Rth j-a	650	°C/W

### **ELECTRICAL CHARACTERISTICS (TA = +25°C)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0 mA	-	-	100	nA	
Emitter Cut-off Current	ІЕВО	V <sub>EB</sub> = 1 V, I <sub>C</sub> = 0 mA	_	-	100	nA	
DC Current Gain	hfE Note 1	Vce = 2 V, Ic = 5 mA	50	70	100	-	
RF Characteristics							
Gain Bandwidth Product	fτ	Vce = 3 V, Ic = 10 mA, f = 2 GHz	20	25	-	GHz	
Insertion Power Gain	S <sub>21e</sub>  ²	Vce = 2 V, Ic = 5 mA, f = 2 GHz	14	17	-	dB	
Noise Figure	NF	$V_{CE} = 2 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ f} = 2 \text{ GHz},$ $Z_{S} = Z_{opt}$	-	1.2	1.5	dB	
Reverse Transfer Capacitance	Cre Note 2	VcB = 2 V, IE = 0 mA, f = 1 MHz	-	0.08	0.12	pF	
Maximum Stable Power Gain	MSG Note 3	Vce = 2 V, Ic = 5 mA, f = 2 GHz	_	22	-	dB	
Gain 1 dB Compression Output Power	Po (1 dB)	VcE = 2 V, Ic = 5 mA Note 4, f = 2 GHz	_	5	-	dBm	
3rd Order Intermodulation Distortion Output Intercept Point	OIP <sub>3</sub>	Vce = 2 V, Ic = 5 mA <sup>Note 4</sup> , f = 2 GHz	-	15	-	dBm	

**Notes 1.** Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

2. Collector to base capacitance when the emitter grounded

3. MSG = 
$$\frac{S_{21}}{S_{12}}$$

4. Collector current when Po (1 dB) is output

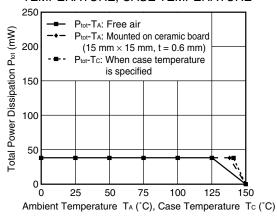
### **hfe CLASSIFICATION**

Rank	FB	
Marking	T78	
h <sub>FE</sub> Value	50 to 100	

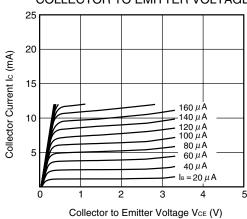
### **★ TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)**

### Thermal/DC Characteristics

### TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE, CASE TEMPERATURE

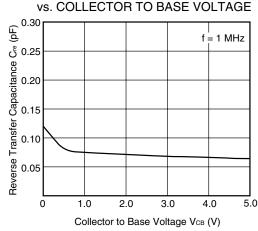


### COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



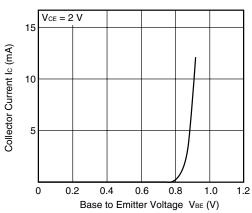
### Capacitance/fr Characteristics

### REVERSE TRANSFER CAPACITANCE

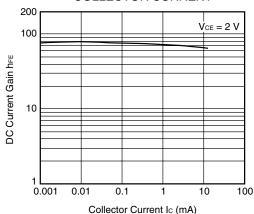


### Remark The graphs indicate nominal characteristics.

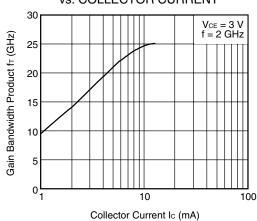
### COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



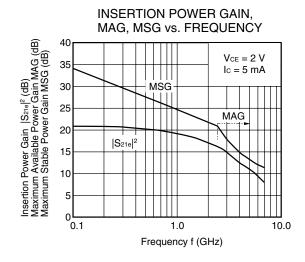
# DC CURRENT GAIN vs. COLLECTOR CURRENT

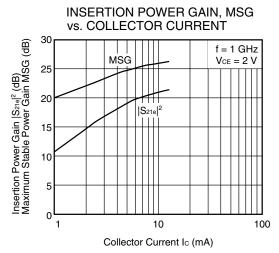


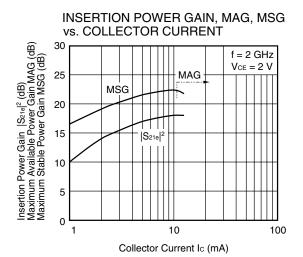
# GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



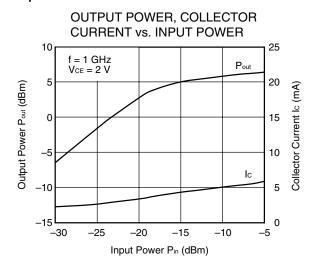
#### **Gain Characteristics**

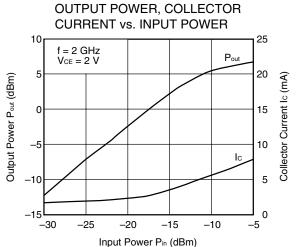






### **Output Characteristics**

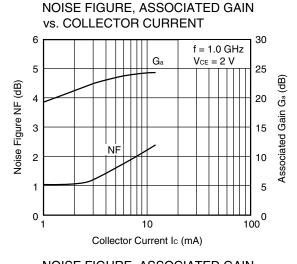


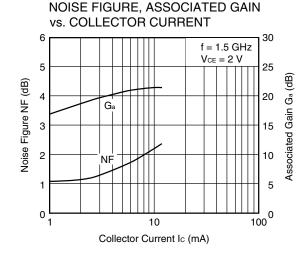


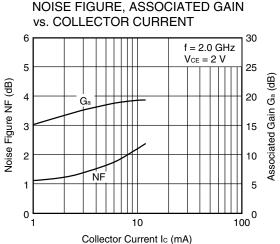
**Remark** The graphs indicate nominal characteristics.

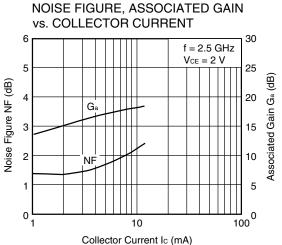
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#### **Noise Characteristics**









**Remark** The graphs indicate nominal characteristics.

### **★** S-PARAMETERS

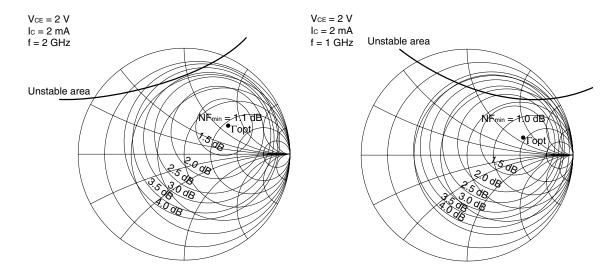
S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$ 

URL http://www.ncsd.necel.com/

### **EQUAL NF CIRCLE**



### **NOISE PARAMETERS**

 $V_{CE} = 2 V$ ,  $I_C = 2 mA$ 

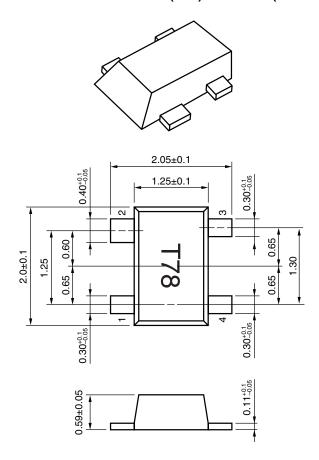
f	NFmin	Ga	Го	opt	Dn/50
(GHz)	(dB)	(dB)	MAG.	ANG.	Rn/50
0.8	0.93	22.9	0.54	13.3	0.47
0.9	0.95	22.2	0.54	14.9	0.47
1.0	0.97	21.6	0.54	16.4	0.47
1.5	1.08	18.8	0.53	24.6	0.45
1.8	1.14	17.5	0.51	30.3	0.43
1.9	1.16	17.1	0.50	32.4	0.42
2.0	1.18	16.7	0.49	34.6	0.41
2.5	1.29	15.2	0.44	47.7	0.35

 $V_{CE} = 2 V$ ,  $I_{C} = 5 mA$ 

f	NFmin	NF <sub>min</sub> G <sub>a</sub> Γορt		- Rn/50	
(GHz)	(dB)	(dB)	MAG.	ANG.	HI/50
0.8	1.59	24.7	0.38	10.7	0.43
0.9	1.60	24.1	0.38	11.9	0.43
1.0	1.60	23.4	0.38	13.2	0.43
1.5	1.62	20.7	0.36	20.5	0.41
1.8	1.63	19.3	0.34	25.7	0.38
1.9	1.63	18.9	0.33	27.5	0.38
2.0	1.63	18.5	0.32	29.4	0.37
2.5	1.65	16.9	0.26	40.1	0.32

### **★ PACKAGE DIMENSIONS**

### FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) PACKAGE (UNIT: mm)



### PIN CONNECTIONS

- 1. Emitter
- 2. Collector
- 3. Emitter
- 4. Base

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